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REMARKS

Present Status of the Application

Claims 1, 4-6, 8-10, 12 and 35-37 were rejected under 35 U.S.C. 102(e) as being

anticipated by Haspeslagh (US 6,580,120) and claim 11 rejected under 35 U.S.C. 103(a)

as being unpatentable over Haspeslagh in view of Schwabe (US 4,257,832).

In response thereto, Applicants have further amended independent claims 1 and 35

and submitted the following remarks, wherein the amendment can be supported by, for

example, FIG. 4 and related paragraphs in the specification. Reconsideration of claims

1, 4-6, 8-12 and 35-37 is respectfully requested.

Interview Summary

The undersigned would like to thank Examiner Warren for granting a

telephonic interview on April 11, 2008, during which a proposed amendment to claim 1

was discussed. More particularly, the undersigned and the examiner discussed the

rejections and the teachings of the Haspeslagh reference in view of the proposed

amendments. After discussing this matter, the examiner acknowledges that Haspeslagh

fails to disclose at least two neighboring conductive pieces (of the split gate) being a part

of one word line. Moreover, there is double coding region for each conductive piece in

the prior art.

Discussion of Rejections under 35 U.S.C. 102(e)

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Claims 1, 4-6, 8-10, 12 and 35-37 were rejected as being anticipated by Haspeslagh.

Please note that independent claims 1 and 35 have been amended.

The features of amended claim 1/35 include that the split gate including the at least

two neighboring conductive pieces shorted with each other is a part of one word line of

a non-volatile memory array including the non-volatile memory cell, and that only one

coding region is defined in the memory cell by the <u>at least two</u> conductive pieces.

Haspeslagh fails to disclose the above features. As shown in Fig. 5 and described

in related paragraphs, <u>one</u> word line includes <u>only one</u> "conductive piece" 7/11, and the

leftmost three "conductive pieces" 7/11 shorted with each other belong to three word

lines W₁-W₃, rather then *one* word line. Moreover, as shown in Fig.3, each memory cell

in Haspeslagh apparently has two coding regions defined by the only one conductive

piece of the memory cell.

Another feature of method claim 35 is that in the programming operation of the

memory cell, θV is applied to the substrate and the <u>source/drain</u> while a first negative

voltage is applied to the split gate, wherein the first negative voltage is sufficiently high

for injecting electrons into the coding region.

Haspeslagh also fails to disclose the above feature of claim 35. In the program

operation of a memory cell in Haspeslagh, the *source* and the *drain* of the memory cell

must be applied with *different voltages* to have two coding regions in one cell (Fig. 3).

Furthermore, the memory cell structure of amended claim 1 is provided for the

sake (lower operating voltage) of the operating method of claim 35, while the operating

method of claim 35 is particularly suitable for the memory cell structure of amended

claim 1. Since the memory cell structure and the operating method of Haspeslagh both

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are quite different from those of the claimed invention, Haspeslagh also cannot suggest

or imply the claimed invention, and thus the claimed invention is non-obvious to one of

ordinary skill in the art in view of Haspeslagh.

For at least the above reasons, Applicants respectfully submit that amended claims

1 & 35 and claims 4-6, 8-10, 12 & 36-37 dependent therefrom all patently define over

the prior art.

Discussion of Rejections under 35 U.S.C. 103(a)

Claim 11 were rejected over Haspeslagh in view of Schwabe. Haspeslagh fails to

disclose or suggest the above features of amended claim 1, as mentioned above. It is

also noted that Schwabe also fails to disclose or suggest the same features.

For at least the above reasons, Applicants respectfully submit that claim 11

dependent from claim 1 also patently define over the prior art.

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CONCLUSION

For at least the foregoing reasons, it is believed that the pending claims 1, 4-6, 8-12 and 35-37 are in proper condition for allowance. If the Examiner believes that a telephone conference would expedite the examination of the above-identified patent application, the Examiner is invited to call the undersigned.

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